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M95160-x M95080-x

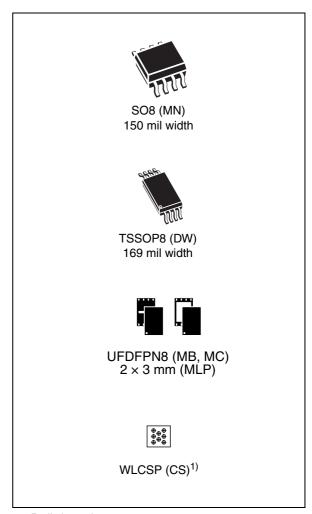
16 Kbit and 8 Kbit serial SPI bus EEPROM with high speed clock

Features

- Compatible with SPI bus serial interface (positive clock SPI modes)
- Single supply voltage:
 - 4.5 V to 5.5 V for M95xxx
 - 2.5 V to 5.5 V for M95xxx-W
 - 1.8 V to 5.5 V for M95xxx-R
 - 1.7 V to 5.5 V for M95xxx-F
- High speed: 10 MHz
- Status Register
- Hardware protection of the Status Register
- Byte and page write (up to 32 bytes)
- Self-timed programming cycle
- Adjustable size read-only EEPROM area
- Enhanced ESD protection
- More than 1 million write cycles
- More than 40-year data retention
- Packages
 - ECOPACK[®] (RoHS compliant)

Table 1. Device summary

Reference	Part number
	M95160
M95160-x	M95160-W
W195160-X	M95160-R
	M95160-F
	M95080
M95080-x	M95080-W
	M95080-R



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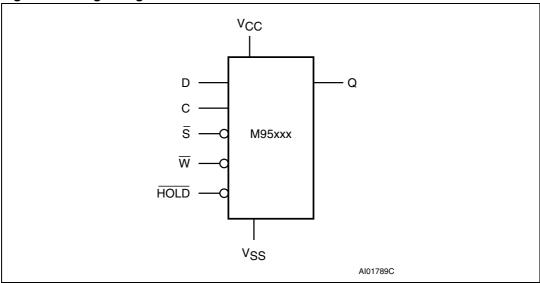


Description M95160-x, M95080-x

1 Description

The M95160-x and M95080-x are electrically erasable programmable memory (EEPROM) devices. They are accessed by a high-speed SPI-compatible bus. The memory array is organized as 2048 x 8 bit (M95160-x), and 1024 x 8 bit (M95080-x).

Figure 1. Logic diagram



The device is accessed by a simple serial interface that is SPI-compatible. The bus signals are C, D and Q, as shown in *Table 2* and *Figure 1*.

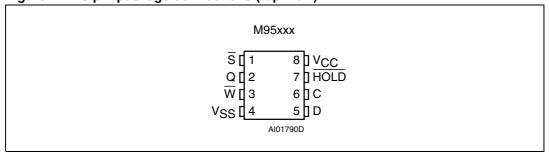
The device is selected when Chip Select (\overline{S}) is taken low. Communications with the device can be interrupted using Hold (\overline{HOLD}) .

Table 2. Signal names

Signal name	Function	Direction
С	Serial Clock	Input
D	Serial Data input	Input
Q	Serial Data output	Output
S	Chip Select	Input
W	Write Protect	Input
HOLD	Hold	Input
V _{CC}	Supply voltage	
V_{SS}	Ground	

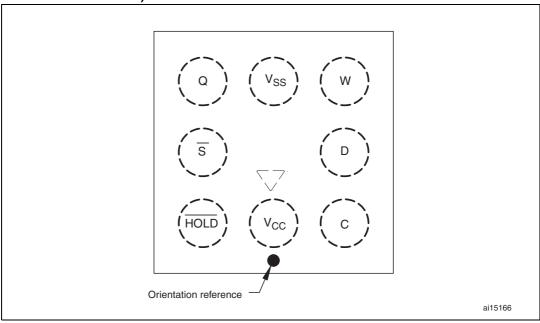
M95160-x, M95080-x Description

Figure 2. 8-pin package connections (top view)



1. See *Package mechanical data* section for package dimensions, and how to identify pin-1.

Figure 3. M95160 WLCSP connections (top view, marking side, with balls on the underside)



Caution:

EEPROM cells loose their charge (and so their binary value) when exposed to ultra violet (UV) light. Consequently, EEPROM dice delivered in wafer form or in WLCSP package by STMicroelectronics must never be exposed to UV light.

Signal description M95160-x, M95080-x

2 Signal description

During all operations, V_{CC} must be held stable and within the specified valid range: V_{CC} (min) to V_{CC} (max).

All of the input and output signals must be held high or low (according to voltages of V_{IH} , V_{OH} , V_{IL} or V_{OL} , as specified in *Table 14.* to *Table 19.*). These signals are described next.

2.1 Serial Data output (Q)

This output signal is used to transfer data serially out of the device. Data is shifted out on the falling edge of Serial Clock (C).

2.2 Serial Data input (D)

This input signal is used to transfer data serially into the device. It receives instructions, addresses, and the data to be written. Values are latched on the rising edge of Serial Clock (C).

2.3 Serial Clock (C)

This input signal provides the timing of the serial interface. Instructions, addresses, or data present at Serial Data Input (D) are latched on the rising edge of Serial Clock (C). Data on Serial Data Output (Q) changes after the falling edge of Serial Clock (C).

2.4 Chip Select (\overline{S})

When this input signal is high, the device is deselected and Serial Data Output (Q) is at high impedance. Unless an internal Write cycle is in progress, the device will be in the Standby Power mode. Driving Chip Select (\overline{S}) low selects the device, placing it in the Active Power mode

After Power-up, a falling edge on Chip Select (\overline{S}) is required prior to the start of any instruction.

2.5 Hold (HOLD)

The Hold (HOLD) signal is used to pause any serial communications with the device without deselecting the device.

During the Hold condition, the Serial Data Output (Q) is high impedance, and Serial Data Input (D) and Serial Clock (C) are Don't Care.

To start the Hold condition, the device must be selected, with Chip Select (\overline{S}) driven low.

M95160-x, M95080-x Signal description

2.6 Write Protect (\overline{W})

The main purpose of this input signal is to freeze the size of the area of memory that is protected against Write instructions (as specified by the values in the BP1 and BP0 bits of the Status Register).

This pin must be driven either high or low, and must be stable during all write instructions.

2.7 V_{CC} supply voltage

 V_{CC} is the supply voltage.

2.8 V_{SS} ground

 V_{SS} is the reference for the V_{CC} supply voltage.

3 Connecting to the SPI bus

These devices are fully compatible with the SPI protocol.

All instructions, addresses and input data bytes are shifted in to the device, most significant bit first. The Serial Data input (D) is sampled on the first rising edge of the Serial Clock (C) after Chip Select (\overline{S}) goes low.

All output data bytes are shifted out of the device, most significant bit first. The Serial Data output (Q) is latched on the first falling edge of the Serial Clock (C) after the instruction (such as the Read from Memory Array and Read Status Register instructions) have been clocked into the device.

Figure 4. shows three devices, connected to an MCU, on an SPI bus. Only one device is selected at a time, so only one device drives the Serial Data output (Q) line at a time, all the others being high impedance.

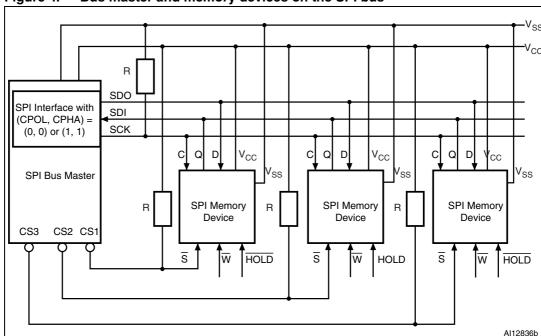


Figure 4. Bus master and memory devices on the SPI bus

1. The Write Protect (\overline{W}) and Hold (\overline{HOLD}) signals should be driven, high or low as appropriate.

Figure 4 shows an example of three memory devices connected to an MCU, on an SPI bus. Only one memory device is selected at a time, so only one memory device drives the Serial Data output (Q) line at a time, the other memory devices are high impedance.

The pull-up resistor R (represented in *Figure 4*) ensures that a device is not selected if the Bus Master leaves the \overline{S} line in the high impedance state.

In applications where the Bus Master may be in a state where all input/output SPI buses are high impedance at the same time (for example, if the Bus Master is reset during the transmission of an instruction), the clock line (C) must be connected to an external pull-down resistor so that, if all inputs/outputs become high impedance, the C line is pulled low (while the \overline{S} line is pulled high): this ensures that \overline{S} and C do not become high at the same time, and so, that the t_{SHCH} requirement is met. The typical value of R is 100 k Ω

3.1 SPI modes

These devices can be driven by a microcontroller with its SPI peripheral running in either of the two following modes:

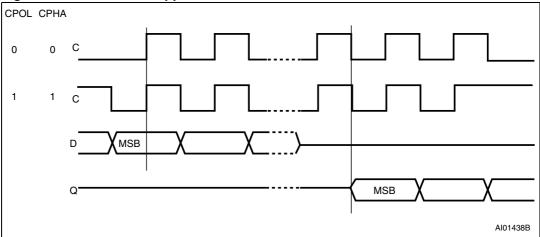
- CPOL=0, CPHA=0
- CPOL=1, CPHA=1

For these two modes, input data is latched in on the rising edge of Serial Clock (C), and output data is available from the falling edge of Serial Clock (C).

The difference between the two modes, as shown in *Figure 5*., is the clock polarity when the bus master is in Stand-by mode and not transferring data:

- C remains at 0 for (CPOL=0, CPHA=0)
- C remains at 1 for (CPOL=1, CPHA=1)

Figure 5. SPI modes supported



Operating features M95160-x, M95080-x

4 Operating features

4.1 Supply voltage (V_{CC})

4.1.1 Operating supply voltage V_{CC}

Prior to selecting the memory and issuing instructions to it, a valid and stable V_{CC} voltage within the specified [V_{CC} (min), V_{CC} (max)] range must be applied (see *Table 9*, *Table 10* and *Table 11*). This voltage must remain stable and valid until the end of the transmission of the instruction and, for a Write instruction, until the completion of the internal write cycle (t_W). In order to secure a stable DC supply voltage, it is recommended to decouple the V_{CC} line with a suitable capacitor (usually of the order of 10 nF to 100 nF) close to the V_{CC}/V_{SS} package pins.

4.1.2 Device reset

In order to prevent inadvertent write operations during power-up, a power-on-reset (POR) circuit is included. At power-up, the device does not respond to any instruction until V_{CC} reaches the POR threshold voltage (this threshold is defined in DC characteristics tables 15, 16, 17, 18, 19 and 20 as V_{RES}).

When V_{CC} passes over the POR threshold, the device is reset and is in the following state:

- in Standby Power mode
- deselected (note that, to be executed, an instruction must be preceded by a falling edge on Chip Select (\overline{S}))
- Status Register value:
 - the Write Enable Latch (WEL) is reset to 0
 - Write In Progress (WIP) is reset to 0
 - The SRWD, BP1 and BP0 bits remain unchanged (non-volatile bits)

When V_{CC} passes over the POR threshold, the device is reset and enters the Standby Power mode. The device must not be accessed until V_{CC} reaches a valid and stable V_{CC} voltage within the specified [V_{CC} (min), V_{CC} (max)] range defined in *Table 9*, *Table 10* and *Table 11*.

4.1.3 Power-up conditions

When the power supply is turned on, V_{CC} rises continuously from V_{SS} to V_{CC} . During this time, the Chip Select (\overline{S}) line is not allowed to float but should follow the V_{CC} voltage. It is therefore recommended to connect the \overline{S} line to V_{CC} via a suitable pull-up resistor (see *Figure 4*).

In addition, the Chip Select (\overline{S}) input offers a built-in safety feature, as the \overline{S} input is edge sensitive as well as level sensitive: after power-up, the device does not become selected until a falling edge has first been detected on Chip Select (\overline{S}) . This ensures that Chip Select (\overline{S}) must have been high, prior to going low to start the first operation.

The V_{CC} voltage has to rise continuously from 0 V up to the minimum V_{CC} operating voltage defined in *Table 9*, *Table 10* and *Table 11* and the rise time must not vary faster than 1 V/ μ s.

M95160-x, M95080-x Operating features

4.1.4 Power-down

During power-down (continuous decrease in the V_{CC} supply voltage below the minimum V_{CC} operating voltage defined in *Table 9*, *Table 10* and *Table 11*), the device must be:

- deselected (Chip Select \overline{S} should be allowed to follow the voltage applied on V_{CC})
- in Standby Power mode (there should not be any internal write cycle in progress).

4.2 Active Power and Standby Power modes

When Chip Select (\overline{S}) is low, the device is selected, and in the Active Power mode. The device consumes I_{CC} , as specified in *Table 14*. to *Table 19*.

When Chip Select (\overline{S}) is high, the device is deselected. If a Write cycle is not currently in progress, the device then goes into the Standby Power mode, and the device consumption drops to I_{CC1} .

4.3 Hold condition

The Hold (HOLD) signal is used to pause any serial communications with the device without resetting the clocking sequence.

During the Hold condition, the Serial Data Output (Q) is high impedance, and Serial Data Input (D) and Serial Clock (C) are Don't Care.

To enter the Hold condition, the device must be selected, with Chip Select (\overline{S}) low.

Normally, the device is kept selected, for the whole duration of the Hold condition. Deselecting the device while it is in the Hold condition, has the effect of resetting the state of the device, and this mechanism can be used if it is required to reset any processes that had been in progress.

The Hold condition starts when the Hold (HOLD) signal is driven low at the same time as Serial Clock (C) already being low.

The Hold condition ends when the Hold ($\overline{\text{HOLD}}$) signal is driven high at the same time as Serial Clock (C) already being low.

4.4 Status Register

Figure 6. shows the position of the Status Register in the control logic of the device. The Status Register contains a number of status and control bits that can be read or set (as appropriate) by specific instructions. See Section 6.3: Read Status Register (RDSR) for a detailed description of the Status Register bits

Operating features M95160-x, M95080-x

4.5 Data protection and protocol control

Non-volatile memory devices can be used in environments that are particularly noisy, and within applications that could experience problems if memory bytes are corrupted. Consequently, the device features the following data protection mechanisms:

- Write and Write Status Register instructions are checked that they consist of a number of clock pulses that is a multiple of eight, before they are accepted for execution.
- All instructions that modify data must be preceded by a Write Enable (WREN)
 instruction to set the Write Enable Latch (WEL) bit. This bit is returned to its reset state
 by the following events:
 - Power-up
 - Write Disable (WRDI) instruction completion
 - Write Status Register (WRSR) instruction completion
 - Write (WRITE) instruction completion
- The Block Protect (BP1, BP0) bits in the Status Register allow part of the memory to be configured as read-only.
- The Write Protect (W) signal allows the Block Protect (BP1, BP0) bits of the Status Register to be protected.

For any instruction to be accepted, and executed, Chip Select (\overline{S}) must be driven high after the rising edge of Serial Clock (C) for the last bit of the instruction, and before the next rising edge of Serial Clock (C).

Two points need to be noted in the previous sentence:

- The 'last bit of the instruction' can be the eighth bit of the instruction code, or the eighth bit of a data byte, depending on the instruction (except for Read Status Register (RDSR) and Read (READ) instructions).
- The 'next rising edge of Serial Clock (C)' might (or might not) be the next bus transaction for some other device on the SPI bus.

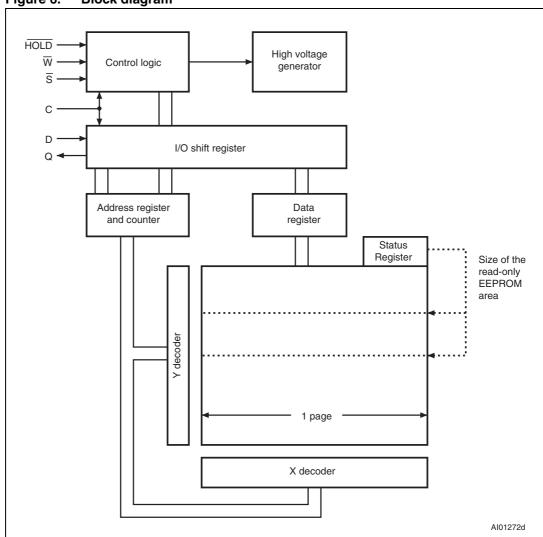
Table 3. Write-protected block size

Status Register bits		Protected block	Protected array addresses		
BP1	BP0	Protected block	M95160-x	M95080-x	
0	0	none	none	none	
0	1	Upper quarter	0600h - 07FFh	0300h - 03FFh	
1	0	Upper half	0400h - 07FFh	0200h - 03FFh	
1	1	Whole memory	0000h - 07FFh	0000h - 03FFh	

5 Memory organization

The memory is organized as shown in Figure 6.

Figure 6. Block diagram



6 Instructions

Each instruction starts with a single-byte code, as summarized in Table 4.

If an invalid instruction is sent (one not contained in *Table 4.*), the device automatically deselects itself.

Table 4. Instruction set

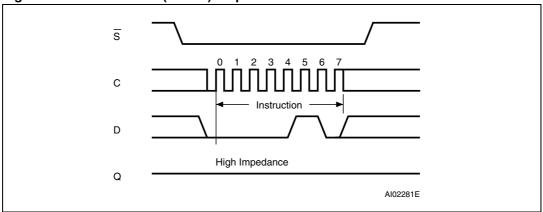
Instruction	Description	Instruction format
WREN	Write Enable	0000 0110
WRDI	Write Disable	0000 0100
RDSR	Read Status Register	0000 0101
WRSR	Write Status Register	0000 0001
READ	Read from Memory Array	0000 0011
WRITE	Write to Memory Array	0000 0010

6.1 Write Enable (WREN)

The Write Enable Latch (WEL) bit must be set prior to each WRITE and WRSR instruction. The only way to do this is to send a Write Enable instruction to the device.

As shown in *Figure 7.*, to send this instruction to the device, Chip Select (\overline{S}) is driven low, and the bits of the instruction byte are shifted in, on Serial Data Input (D). The device then enters a wait state. It waits for the device to be deselected, by Chip Select (\overline{S}) being driven high.

Figure 7. Write Enable (WREN) sequence



M95160-x, M95080-x Instructions

6.2 Write Disable (WRDI)

One way of resetting the Write Enable Latch (WEL) bit is to send a Write Disable instruction to the device.

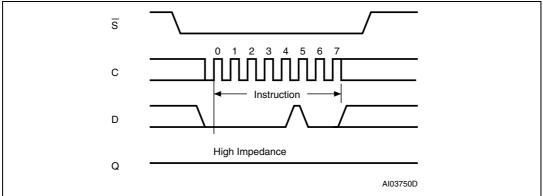
As shown in *Figure 8*., to send this instruction to the device, Chip Select (\overline{S}) is driven low, and the bits of the instruction byte are shifted in, on Serial Data Input (D).

The device then enters a wait state. It waits for a the device to be deselected, by Chip Select (\overline{S}) being driven high.

The Write Enable Latch (WEL) bit, in fact, becomes reset by any of the following events:

- Power-up
- WRDI instruction execution
- WRSR instruction completion
- WRITE instruction completion.

Figure 8. Write Disable (WRDI) sequence



6.3 Read Status Register (RDSR)

The Read Status Register (RDSR) instruction allows the Status Register to be read. The Status Register may be read at any time, even while a Write or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write In Progress (WIP) bit before sending a new instruction to the device. It is also possible to read the Status Register continuously, as shown in *Figure 9*.

The status and control bits of the Status Register are as follows:

6.3.1 WIP bit

The Write In Progress (WIP) bit indicates whether the memory is busy with a Write or Write Status Register cycle. When set to 1, such a cycle is in progress, when reset to 0 no such cycle is in progress.

6.3.2 WEL bit

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1 the internal Write Enable Latch is set, when set to 0 the internal Write Enable Latch is reset and no Write or Write Status Register instruction is accepted.

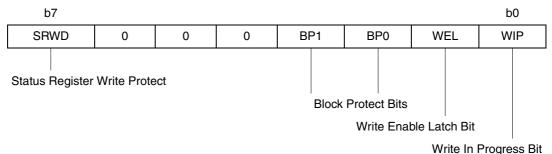
6.3.3 **BP1**, **BP0** bits

The Block Protect (BP1, BP0) bits are non-volatile. They define the size of the area to be software protected against Write instructions. These bits are written with the Write Status Register (WRSR) instruction. When one or both of the Block Protect (BP1, BP0) bits is set to 1, the relevant memory area (as defined in *Table 5*.) becomes protected against Write (WRITE) instructions. The Block Protect (BP1, BP0) bits can be written provided that the Hardware Protected mode has not been set.

6.3.4 SRWD bit

The Status Register Write Disable (SRWD) bit is operated in conjunction with the Write Protect (\overline{W}) signal. The Status Register Write Disable (SRWD) bit and Write Protect (\overline{W}) signal allow the device to be put in the Hardware Protected mode (when the Status Register Write Disable (SRWD) bit is set to 1, and Write Protect (\overline{W}) is driven low). In this mode, the non-volatile bits of the Status Register (SRWD, BP1, BP0) become read-only bits and the Write Status Register (WRSR) instruction is no longer accepted for execution.

Table 5. Status Register format



M95160-x, M95080-x Instructions

Figure 9. Read Status Register (RDSR) sequence

6.4 Write Status Register (WRSR)

The Write Status Register (WRSR) instruction allows new values to be written to the Status Register. Before it can be accepted, a Write Enable (WREN) instruction must previously have been executed.

The Write Status Register (WRSR) instruction is entered by driving Chip Select (\overline{S}) low, followed by the instruction code, the data byte on Serial Data input (D) and Chip Select (\overline{S}) driven high. Chip Select (\overline{S}) must be driven high after the rising edge of Serial Clock (C) that latches in the eighth bit of the data byte, and before the next rising edge of Serial Clock (C). Otherwise, the Write Status Register (WRSR) instruction is not executed.

The instruction sequence is shown in Figure 10.

Driving the Chip Select (\overline{S}) signal high at a byte boundary of the input data triggers the self-timed write cycle that takes t_W to complete (as specified in *Table 21*, *Table 22*, *Table 23*, *Table 24*, *Table 26* and *Table 27*).

While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write in progress (WIP) bit: the WIP bit is 1 during the self-timed write cycle t_{W} , and, 0 when the write cycle is complete. The WEL bit (Write enable latch) is also reset at the end of the write cycle t_{W} .

The Write Status Register (WRSR) instruction allows the user to change the values of the BP1, BP0 and SRWD bits:

- The Block Protect (BP1, BP0) bits define the size of the area that is to be treated as read only, as defined in *Table 3*.
- The SRWD bit (Status Register Write Disable bit), in accordance with the signal read on the Write Protect pin (W), allows the user to set or reset the Write protection mode of the Status Register itself, as defined in *Table 6*. When in Write-protected mode, the Write Status Register (WRSR) instruction is not executed.

The contents of the SRWD and BP1, BP0 bits are updated after the completion of the WRSR instruction, including the t_W Write cycle.

The Write Status Register (WRSR) instruction has no effect on the b6, b5, b4, b1, b0 bits in the Status Register. Bits b6, b5, b4 are always read as 0.

Table 6. Protection modes

W	SRWD	Mode	Write protection of the	Memory content		
signal	bit	Mode	Status Register	Protected area ⁽¹⁾	Unprotected area ⁽¹⁾	
1	0		Status Register is writable (if the WREN instruction has set the WEL bit) The values in the BP1 and BP0 bits can be changed			
0	0	Software-		Write-protected	Ready to accept Write instructions	
1	1	protected (SPM)				
0	1	Hardware- protected (HPM)	Status Register is Hardware write-protected The values in the BP1 and BP0 bits cannot be changed	Write-protected	Ready to accept Write instructions	

^{1.} As defined by the values in the Block Protect (BP1, BP0) bits of the Status Register, as shown in Table 3.

M95160-x, M95080-x Instructions

The protection features of the device are summarized in *Table 6*.

When the Status Register Write Disable (SRWD) bit in the Status Register is 0 (its initial delivery state), it is possible to write to the Status Register (provided that the WEL bit has previously been set by a WREN instruction), regardless of the logic level applied on the Write Protect (\overline{W}) input pin.

When the Status Register Write Disable (SRWD) bit in the Status Register is set to 1, two cases need to be considered, depending on the state of the Write Protect (\overline{W}) input pin:

- If Write Protect (\overline{W}) is driven high, it is possible to write to the Status Register (provided that the WEL bit has previously been set by a WREN instruction.
- If Write Protect (W) is driven low, it is not possible to write to the Status Register even if the WEL bit has previously been set by a WREN instruction. (Attempts to write to the Status Register are rejected, and are not accepted for execution). As a consequence, all the data bytes in the memory area, which are software-protected (SPM) by the Block Protect (BP1, BP0) bits in the Status Register, are also hardware-protected against data modification.

Regardless of the order of the two events, the Hardware-protected mode (HPM) can be entered by:

- either setting the SRWD bit after driving the Write Protect (W) input pin low
- or driving the Write Protect (W) input pin low after setting the SRWD bit

Once the Hardware-protected mode (HPM) has been entered, the only way of exiting it is to pull high the Write Protect (\overline{W}) input pin.

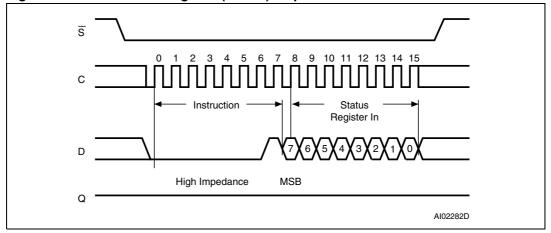
If the Write Protect (\overline{W}) input pin is permanently tied high, the Hardware-protected mode (HPM) can never be activated, and only the Software-protected mode (SPM), using the Block Protect (BP1, BP0) bits in the Status Register, can be used.

Table 7. Address range bits⁽¹⁾

Device	M95160-x	M95080-x
Address bits	A10-A0	A9-A0

b15 to b11 are Don't Care on the M95160-x. b15 to b10 are Don't Care on the M95080-x.

Figure 10. Write Status Register (WRSR) sequence



6.5 Read from Memory Array (READ)

As shown in *Figure 11*., to send this instruction to the device, Chip Select (\overline{S}) is first driven low. The bits of the instruction byte and address bytes are then shifted in, on Serial Data Input (D). The address is loaded into an internal address register, and the byte of data at that address is shifted out, on Serial Data Output (Q).

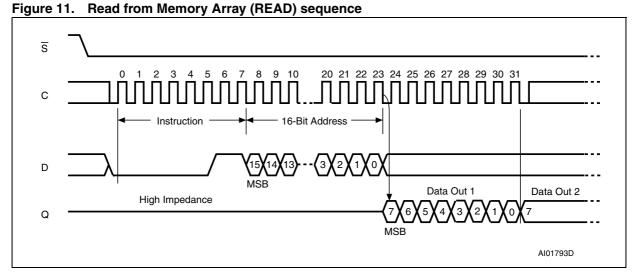
If Chip Select (\overline{S}) continues to be driven low, the internal address register is automatically incremented, and the byte of data at the new address is shifted out.

When the highest address is reached, the address counter rolls over to zero, allowing the Read cycle to be continued indefinitely. The whole memory can, therefore, be read with a single READ instruction.

The Read cycle is terminated by driving Chip Select (\overline{S}) high. The rising edge of the Chip Select (\overline{S}) signal can occur at any time during the cycle.

The first byte addressed can be any byte within any page.

The instruction is not accepted, and is not executed, if a Write cycle is currently in progress.



1. Depending on the memory size, as shown in *Table 7*., the most significant address bits are Don't Care.

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6.6 Write to Memory Array (WRITE)

As shown in *Figure 12*., to send this instruction to the device, Chip Select (\overline{S}) is first driven low. The bits of the instruction byte, address byte, and at least one data byte are then shifted in, on Serial Data Input (D).

The instruction is terminated by driving Chip Select (\overline{S}) high at a byte boundary of the input data. The self-timed Write cycle, triggered by the Chip Select (\overline{S}) rising edge, continues for a period t_W (as specified in *Table 22*. to *Table 26*.), at the end of which the Write in Progress (WIP) bit is reset to 0.

In the case of *Figure 12*., Chip Select (\overline{S}) is driven high after the eighth bit of the data byte has been latched in, indicating that the instruction is being used to write a single byte. If, though, Chip Select (\overline{S}) continues to be driven low, as shown in *Figure 13*., the next byte of input data is shifted in, so that more than a single byte, starting from the given address towards the end of the same page, can be written in a single internal Write cycle.

Each time a new data byte is shifted in, the least significant bits of the internal address counter are incremented. If the number of data bytes sent to the device exceeds the page boundary, the internal address counter rolls over to the beginning of the page, and the previous data there are overwritten with the incoming data. (The page size of these devices is 32 bytes).

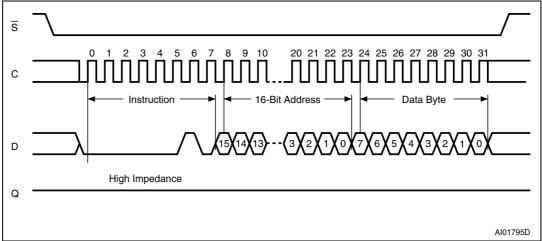
The instruction is not accepted, and is not executed, under the following conditions:

- if the Write Enable Latch (WEL) bit has not been set to 1 (by executing a Write Enable instruction just before)
- if a Write cycle is already in progress
- if the device has not been deselected, by Chip Select (\overline{S}) being driven high, at a byte boundary (after the eighth bit, b0, of the last data byte that has been latched in)
- if the addressed page is in the region protected by the Block Protect (BP1 and BP0) hits

Note:

The self-timed write cycle t_W is internally executed as a sequence of two consecutive events: [Erase addressed byte(s)], followed by [Program addressed byte(s)]. An erased bit is read as "0" and a programmed bit is read as "1".

Figure 12. Byte Write (WRITE) sequence



^{1.} Depending on the memory size, as shown in *Table 7.*, the most significant address bits are Don't Care.

Figure 13. Page Write (WRITE) sequence

1. Depending on the memory size, as shown in *Table 7*., the most significant address bits are Don't Care.

M95160-x, M95080-x Delivery state

7 Delivery state

7.1 Initial delivery state

The device is delivered with the memory array set at all 1s (FFh). The Status Register Write Disable (SRWD) and Block Protect (BP1 and BP0) bits are initialized to 0.

8 Maximum rating

Stressing the device outside the ratings listed in *Table 8*. may cause permanent damage to the device. These are stress ratings only, and operation of the device at these, or any other conditions outside those indicated in the operating sections of this specification, is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 8. Absolute maximum ratings

Symbol	Parameter		Max.	Unit
T _A	Ambient operating temperature		130	°C
T _{STG}	Storage temperature	-65	– 65 150	
T _{LEAD}	Lead temperature during soldering	See note (1)		°C
V _O	Output voltage	-0.50	V _{CC} +0.6	V
VI	Input voltage	-0.50	6.5	V
V _{CC}	Supply voltage	-0.50	6.5	V
V _{ESD}	Electrostatic discharge voltage (human body model) ⁽²⁾	-4000	4000	V

Compliant with JEDEC Std J-STD-020C (for small body, Sn-Pb or Pb assembly), the ST ECOPACK[®]
7191395 specification, and the European directive on Restrictions on Hazardous Substances (RoHS)
2002/95/EU

^{2.} AEC-Q100-002 (compliant with JEDEC Std JESD22-A114, C1=100 pF, R1=1500 Ω , R2=500 Ω)